

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
40V	3.1mΩ@10V	100A
	4mΩ@4.5V	



合肥矽普半导体

Siliup Semiconductor Technology Co., Ltd

技术 品质 服务

www.siliup.com

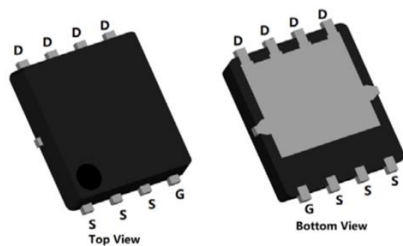
Feature

- Fast switching speed
- Surface mount package
- ROHS Compliant & Halogen-Free
- 100% Single Pulse avalanche energy Test

Applications

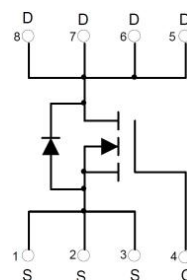
- DC-DC Converters.
- Motor Control.

Package

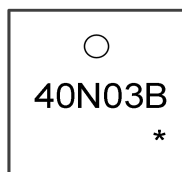


PDFN5X6-8L

Circuit diagram



Marking



40N03B
*

:Device Code
:Month Code

Order Information

Device	Package	Unit/Tape
SP40N03BNK	PDFN5X6-8L	5000

Absolute maximum ratings (Ta=25°C, unless otherwise noted)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	40	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current (Tc=25°C)	I_D	100	A
Continuous Drain Current (Tc=100°C)	I_D	67	A
Pulse Drain Current Tested	I_{DM}	400	A
Single pulsed avalanche energy ¹	E_{AS}	289	mJ
Power Dissipation (Tc=25°C)	P_D	80	W
Thermal Resistance Junction-to-Case	$R_{\theta JC}$	1.6	°C/W
Storage Temperature Range	T_{STG}	-55 to 150	°C
Operating Junction Temperature Range	T_J	-55 to 150	°C

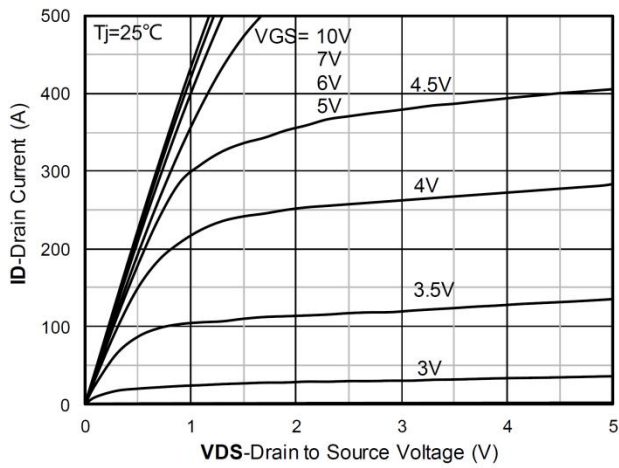
Electrical characteristics (Ta=25°C, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	VGS=0V , ID=250uA	30	-	-	V
Drain-Source Leakage Current	Idss	VDS=24V , VGS=0V , TJ=25℃	-	-	1	uA
Gate-Source Leakage Current	IGSS	VGS=±20V , VDS=0V	-	-	±100	nA
Gate Threshold Voltage	VGS(th)	VGS=VDS , ID =250uA	1.0	1.5	2.5	V
Static Drain-Source On-Resistance	RDS(ON)	VGS =10V, ID =20A	-	3.1	3.9	mΩ
		VGS =4.5V, ID =10A	-	4	5.5	
Dynamic characteristics						
Input Capacitance	Ciss	VDS=20V , VGS=0V , f=1MHz	-	5400	-	pF
Output Capacitance	Coss		-	970	-	
Reverse Transfer Capacitance	Crss		-	380	-	
Total Gate Charge	Qg	VDS=20V , VGS=10V , ID=20A	-	75	-	nC
Gate-Source Charge	Qgs		-	10.5	-	
Gate-Drain Charge	Qgd		-	17	-	
Switching Characteristics						
Turn-On Delay Time	Td(on)	VDD=20V VGS=10V , RG=3Ω, ID=2A	-	15	-	nS
Rise Time	Tr		-	18	-	
Turn-Off Delay Time	Td(off)		-	52	-	
Fall Time	Tf		-	23	-	
Diode Characteristics						
Diode Forward Voltage	VSD	VGS=0V , IS=1A , TJ=25℃	-	-	1.2	V
Diode Continuous Current	IS		-	-	100	A
Reverse recover time	Trr	Is=20A, di/dt=100A/us, Tj=25℃	-	23	-	nS
Reverse recovery charge	Qrr		-	12	-	nC

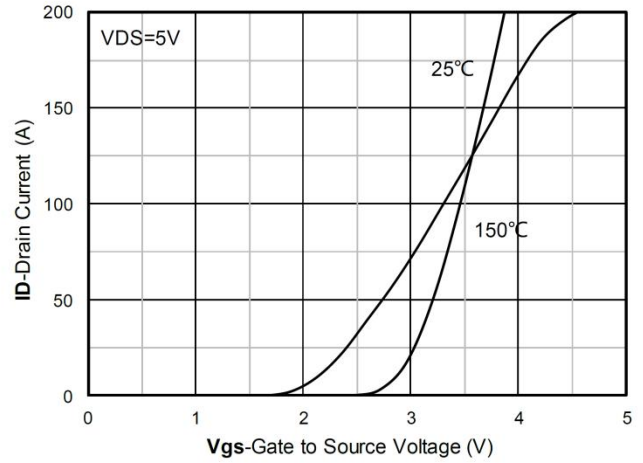
Note:

- The EAS Test condition is $V_{DD}=20V, V_{GS}=10V, L=0.5mH, R_G=25\Omega$

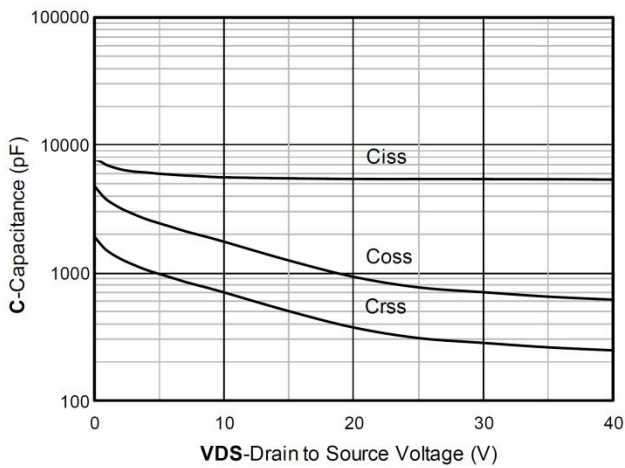
Typical Characteristics



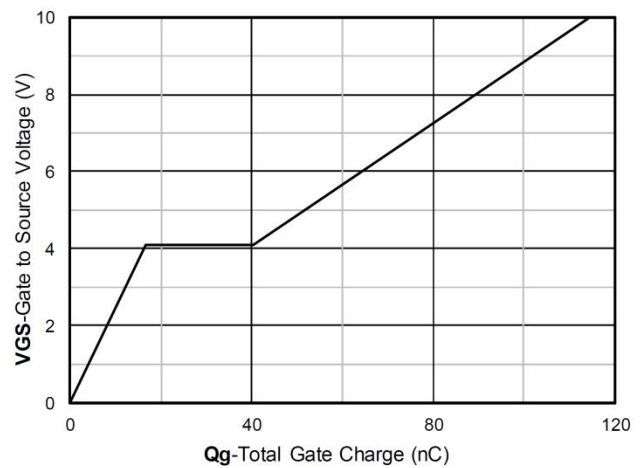
Output Characteristics



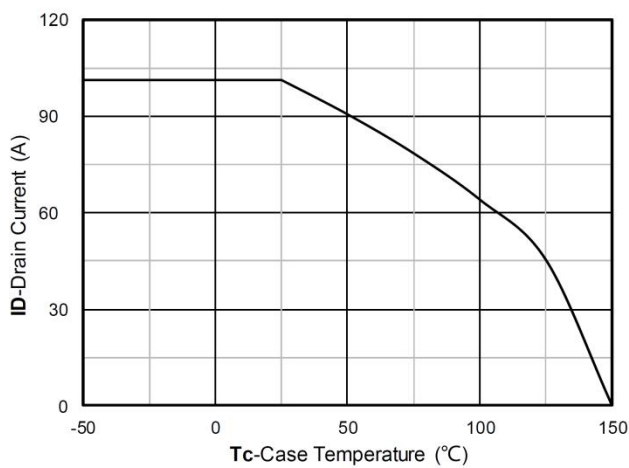
Transfer Characteristics



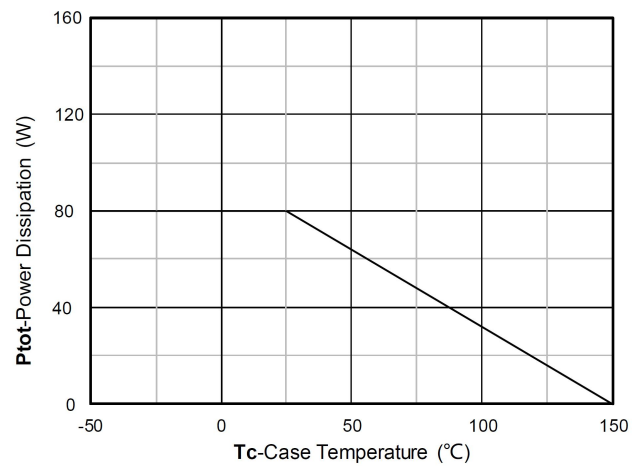
Capacitance Characteristics



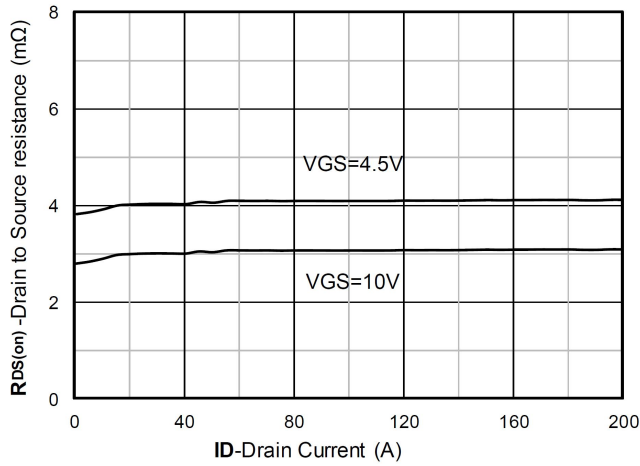
Gate Charge



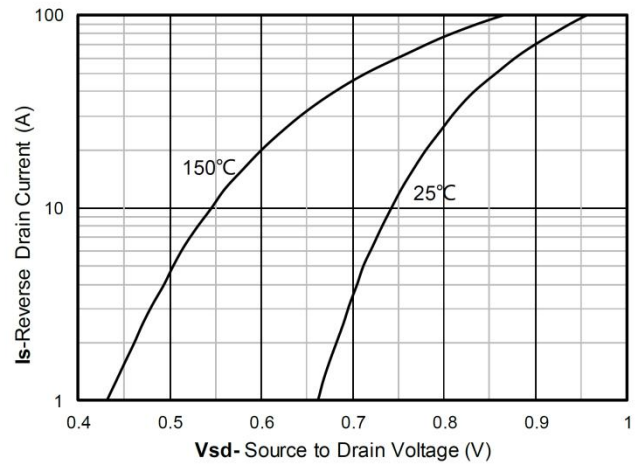
Current dissipation



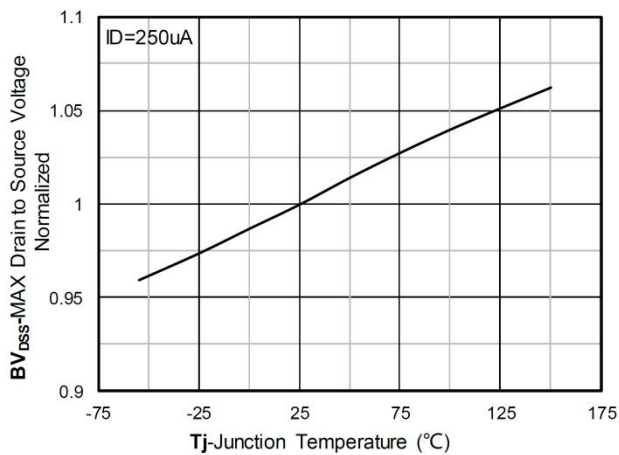
Power dissipation



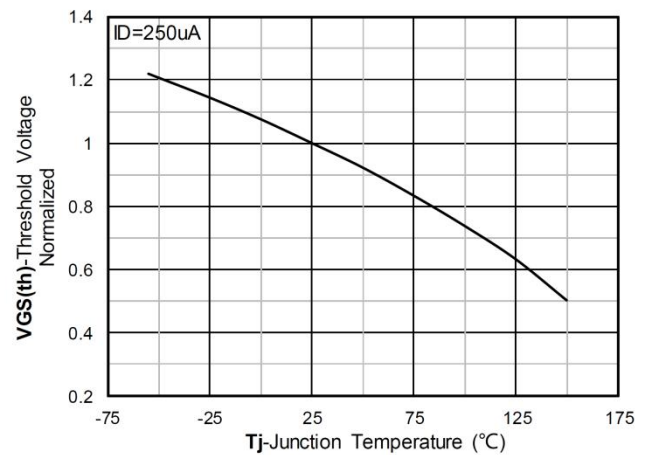
$R_{DS(on)}$ VS Drain Current



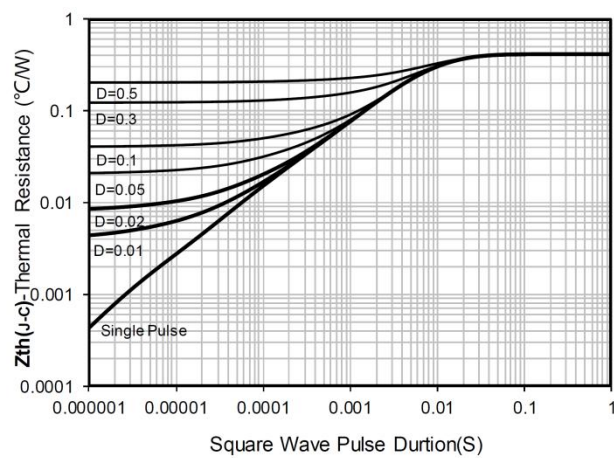
Forward characteristics of reverse diode



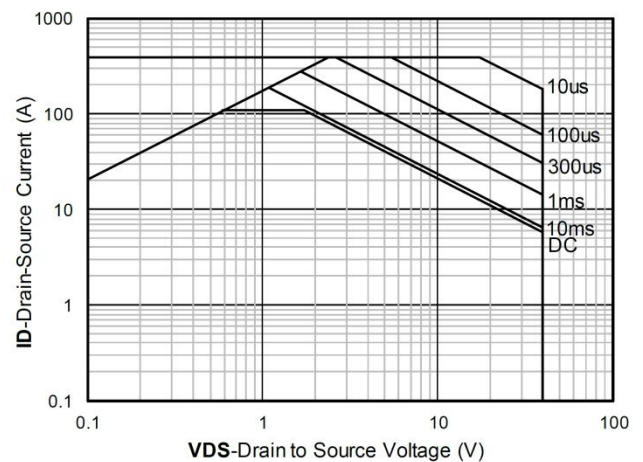
Normalized breakdown voltage



Normalized Threshold voltage

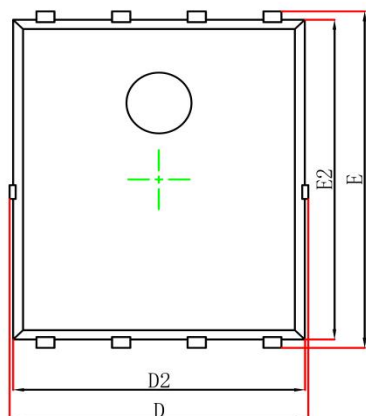


Maximum Transient Thermal Impedance

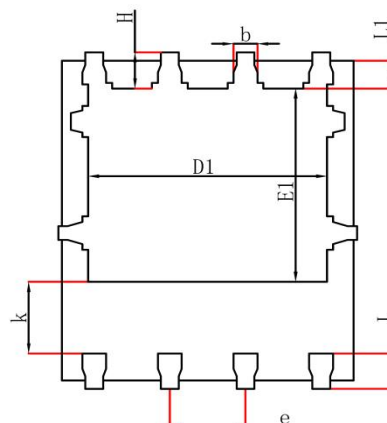


Safe Operation Area

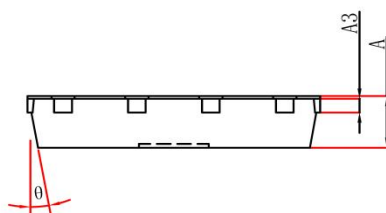
PDFN5X6-8L Package Information



Top View
[顶视图]



Bottom View
[背视图]



Side View
[侧视图]

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.000	0.035	0.039
A3	0.254REF.		0.010REF.	
D	4.944	5.096	0.195	0.201
E	5.974	6.126	0.235	0.241
D1	3.910	4.110	0.154	0.162
E1	3.375	3.575	0.133	0.141
D2	4.824	4.976	0.190	0.196
E2	5.674	5.826	0.223	0.229
k	1.190	1.390	0.047	0.055
b	0.350	0.450	0.014	0.018
e	1.270TYP.		0.050TYP.	
L	0.559	0.711	0.022	0.028
L1	0.424	0.576	0.017	0.023
H	0.574	0.726	0.023	0.029
θ	10°	12°	10°	12°

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [MOSFETs](#) category:

Click to view products by [Siliup](#) manufacturer:

Other Similar products are found below :

[MCH3443-TL-E](#) [MCH6422-TL-E](#) [NTNS3A92PZT5G](#) [IRFD120](#) [2SK2464-TL-E](#) [2SK3818-DL-E](#) [2SJ277-DL-E](#) [2SK2267\(Q\)](#) [MIC4420CM-TR](#) [IRFS350](#) [IPS70R2K0CEAKMA1](#) [AON6932A](#) [2SK2614\(TE16L1,Q\)](#) [DMN1017UCP3-7](#) [EFC2J004NUZTDG](#) [SCM040600](#) [NTE2384](#) [2N7000TA](#) [DMN2080UCB4-7](#) [DMN61D9UWQ-13](#) [US6M2GTR](#) [DMN31D5UDJ-7](#) [DMP22D4UFO-7B](#) [DMN1006UCA6-7](#) [DMN16M9UCA6-7](#) [STF5N65M6](#) [IRF40H233XTMA1](#) [STU5N65M6](#) [DMN13M9UCA6-7](#) [STU7N60DM2](#) [DMTH10H4M6SPS-13](#) [DMN2990UFB-7B](#) [2N7002W-G](#) [MCQ7328-TP](#) [IPB45P03P4L11ATMA2](#) [BXP4N65F](#) [BXP2N20L](#) [BXP2N65D](#) [TSM60NB380CP](#) [ROG](#) [SLF10N65ABV2](#) [IRF9395MTRPBF](#) [FCMT080N65S3](#) [NTD5C632NLT4G](#) [NTMFS0D55N03CGT1G](#) [NTMFS1D15N03CGT1G](#) [NTMTS0D4N04CTXG](#) [NTMYS2D1N04CLTWG](#) [NVD360N65S3T4G](#) [NVD5C464NLT4G](#) [NVMTS001N06CLTXG](#)